## **SPICE Device Model Si4848DY**



Vishay Siliconix

## N-Channel 150 V (D-S) MOSFET

### DESCRIPTION

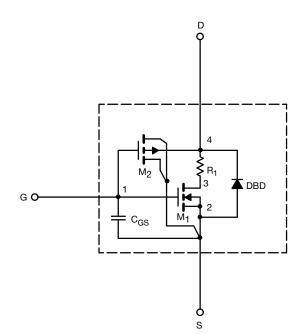
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge

## SUBCIRCUIT MODEL SCHEMATIC



#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.





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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	2.8	-	V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS}$ = $\geq$ 5 V, $V_{GS}$ = 10 V	76	-	А
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.5 \text{ A}$	0.0065	0.068	Ω
		$V_{GS} = 6 V$ , $I_D = 3 A$	0.0078	0.076	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 5 \text{ A}$	12	15	S
Diode Forward Voltage	V <sub>SD</sub>	$I_{S} = 2.5 \text{ A}, V_{GS} = 0 \text{ V}$	0.76	0.75	V
Dynamic <sup>b</sup>					
Total Gate Charge	Qg	$V_{DS}$ = 75 V, $V_{GS}$ = 10 V, $I_{D}$ = 3.5 A	18	17	nC
Gate-Source Charge	Q <sub>gs</sub>		3.2	32	
Gate-Drain Charge	Q <sub>gd</sub>		6	6	
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DD} = 75 \text{ V}, \text{ R}_{\text{L}} = 21 \Omega$ $\text{I}_{\text{D}} = 3.5 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 6 \Omega$ $\text{I}_{\text{F}} = 2.5 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$	12	9	ns
Rise Time	t <sub>r</sub>		16	10	
Turn-Off Delay Time	t <sub>d(off)</sub>		19	24	
Fall Time	t <sub>f</sub>		23	17	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>		52	45	

Notes

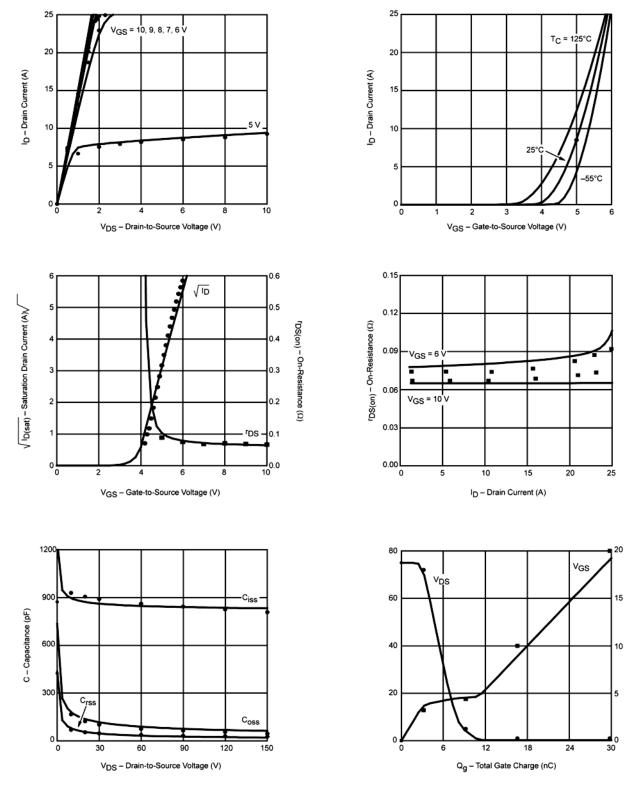
a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.



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## COMPARISON OF MODEL WITH MEASURED DATA (T<sub>J</sub> = 25 °C, unless otherwise noted)



#### Note

• Dots and squares represent measured data.

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